NSN 5961-01-123-2086

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-123-2086 **Inclosure Material:** Glass **Overall Length:** Between 0.140 inches and 0.165 inches **Terminal Length:** Between 0.900 inches and 1.100 inches **Overall Diameter:** Between 0.135 inches and 0.180 inches **Function For Which Designed:** Transient suppressor **End Application:** Radar e/i fscm 76301 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 26.4 breakdown voltage, dc **Current Rating Per Characteristic:** 50.00 milliamperes forward current, total rms nanoamperes **Power Rating Per Characteristic:** 1500.0 watts small-signal input power, common-collector of standard range **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/516 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig: A110a0

No